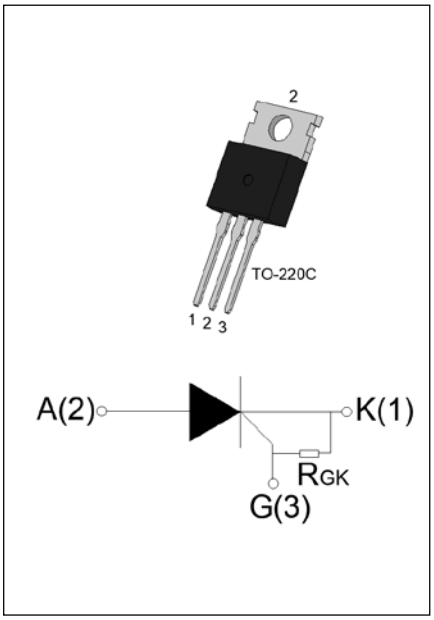
JR0405C 4A SCR

Rev.A.1.1

DESCRIPTION:

The JR0405C SCR with the parallel resistor between Gate and Cathode, R_{GK}=10~80kΩ, is especially recommended for use on straight hair, igniter, anion generator, etc. Package TO-220C is RoHS compliant.



MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$	4	A
V_{DRM}/V_{RRM}	600	V
I_{GT}	≤200	μA

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	T_{stg}	-40-150	℃
Operating junction temperature range	T_j	-40-125①	℃
Repetitive peak off-state voltage (T_j=25℃)	V_{DRM}	600	V
Repetitive peak reverse voltage (T_j=25℃)	V_{RRM}	600	V
Average on-state current (T_C≤109℃)	$I_{T(AV)}$	2.5	A
RMS on-state current (T_C≤109℃)	$I_{T(RMS)}$	4	A
Non repetitive surge peak on-state current (t_p=10ms , T_j=25℃)	I_{TSM}	40	A
Non repetitive surge peak on-state current (t_p=8.3ms , T_j=25℃)		44	
I^2t value for fusing (t_p=10ms , T_j=25℃)	I^2t	8	A^2s
Critical rate of rise of on-state current (I_G=2×I_{GT} , f=100Hz , T_j=125℃)	dI/dt	50	A/μs
Peak gate current (t_p=20μs, T_j=125℃)	I_{GM}	2	A
Average gate power dissipation (T_j=125℃)	$P_{G(AV)}$	0.5	W

Peak gate power	P_{GM}	5	W
Peak pulse voltage (T_j=25℃; non-repetitive,off-state;FIG.7)	V_{pp}	0.5	kV

NOTE 1: Operating junction temperature T_j is up to 125℃ when a resistor ≤1kΩ is connected between Gate and Cathode. Without this resistor, the T_j is up to 110℃ only.

ELECTRICAL CHARACTERISTICS (T_j=25℃ unless otherwise specified)

Symbol	Test Condition	Value			Unit
		MIN.	TYP.	MAX.	
I_{GT}	V_D=12V R_L=33Ω	-	50	200	μA
V_{GT}		-	0.6	0.8	V
V_{GD}	V_D=V_{DRM} T_j=125℃	0.2	-	-	V
I_L	I_G=1.2 I_{GT}	-	-	6	mA
I_H	I_T=0.1A	-	-	5	mA
dV/dt	V_D=400V T_j=125℃ R_{GK}=1kΩ	50	-	-	V/μs
	V_D=400V T_j=125℃ R_{GK}=220Ω	250	-	-	
t_{on}	I_G=10mA I_A=20mA I_R=2mA T_j=25℃	-	2	-	μs
t_{off}		-	50	-	

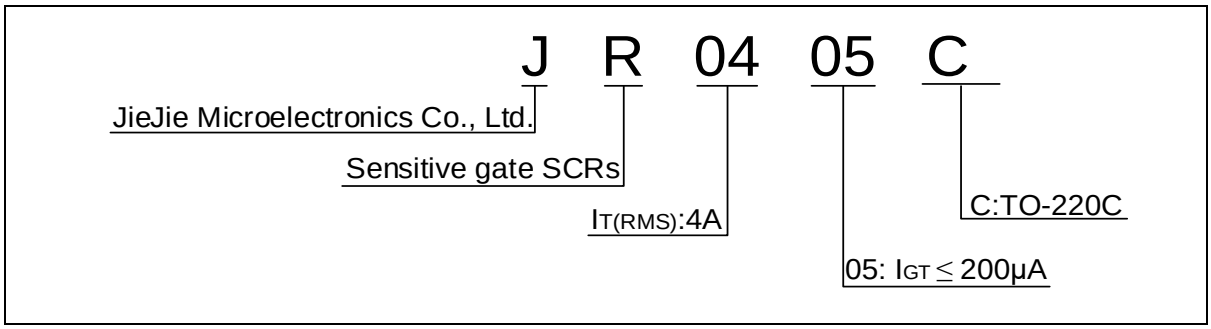
STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX.)	Unit
V_{TM}	I_{TM}=8A t_p=380μs	T_j=25℃	1.6	V
V_{TO}	Threshold voltage	T_j=125℃	0.64	V
R_D	Dynamic resistance	T_j=125℃	0.08	Ω
I_{DRM}	V_D=V_{DRM} V_R=V_{RRM}	T_j=25℃	5	μA
I_{RRM}		T_j=125℃	0.5	mA

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	junction to case (DC)	3	℃/W
$R_{th(j-a)}$	junction to ambient (DC)	40	℃/W

ORDERING INFORMATION



MARKING

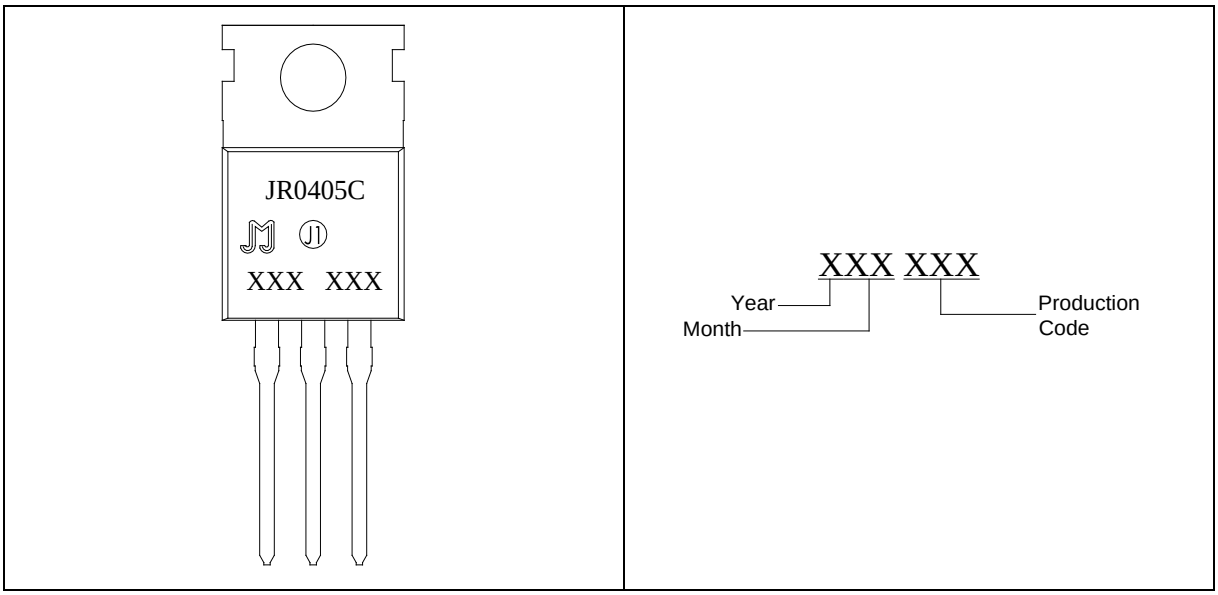


FIG.1: Maximum power dissipation versus RMS on-state current

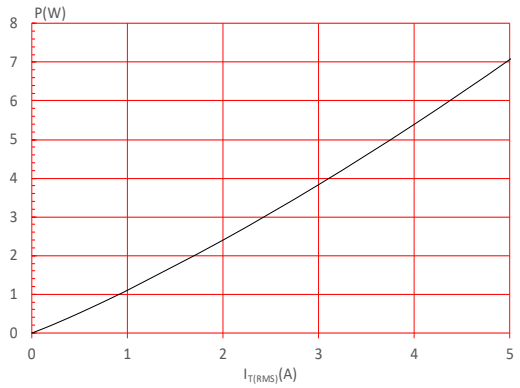


FIG.2: RMS on-state current versus case temperature

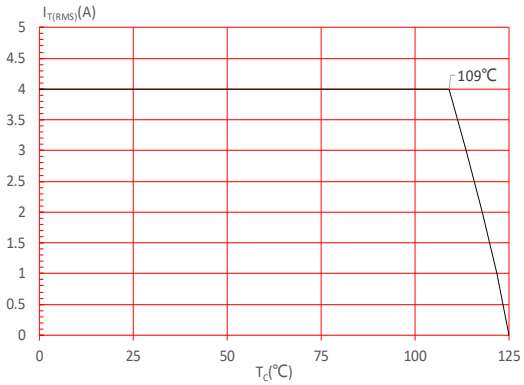


FIG.3: Surge peak on-state current versus number of cycles

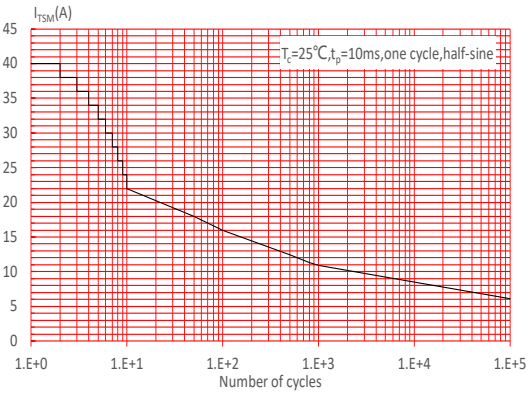


FIG.4: On-state characteristics

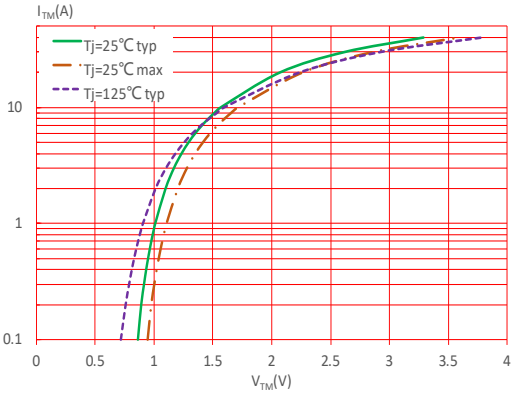


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width t_p<10ms, and corresponding value of I^2t (dI/dt<50A/μs)

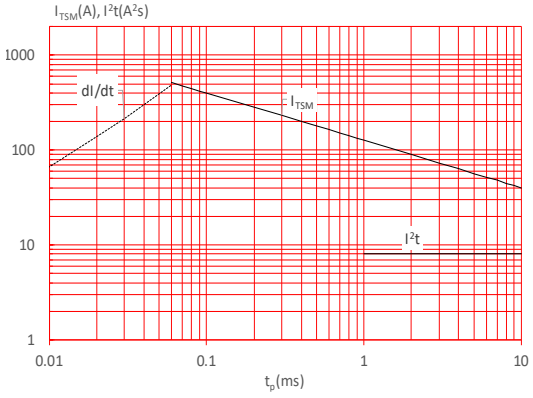


FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature

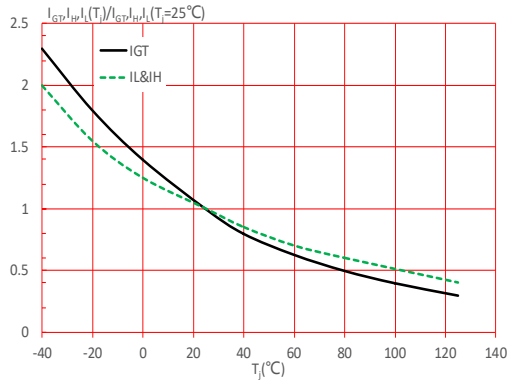
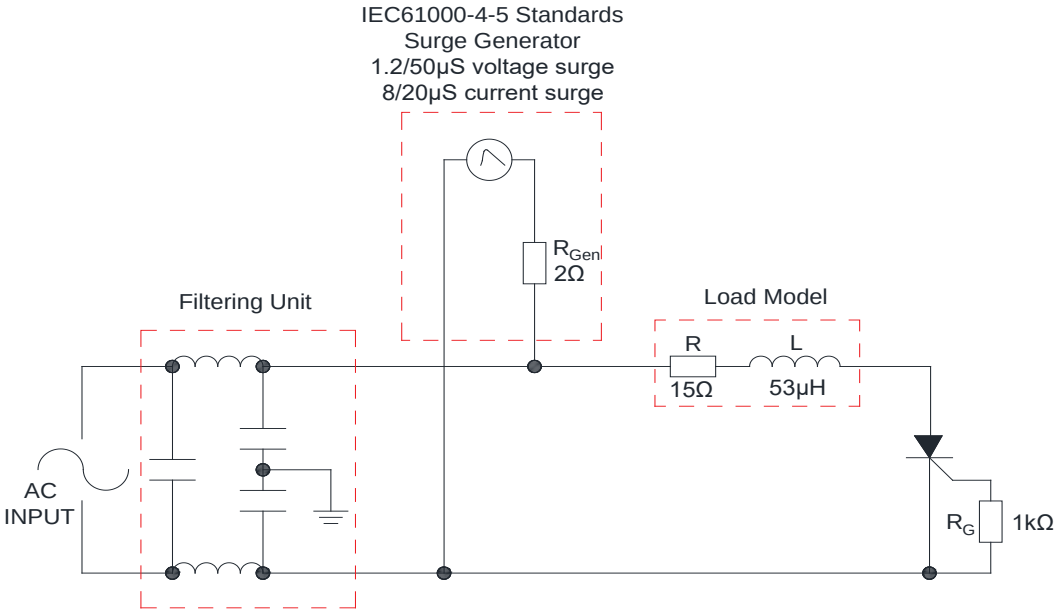


FIG.7：Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



LEAD FORMING AND SOLDERING

Refer to the application note “Assembly Instructions for Thyristors in Through-hole Package” released by JieJie Microelectronics

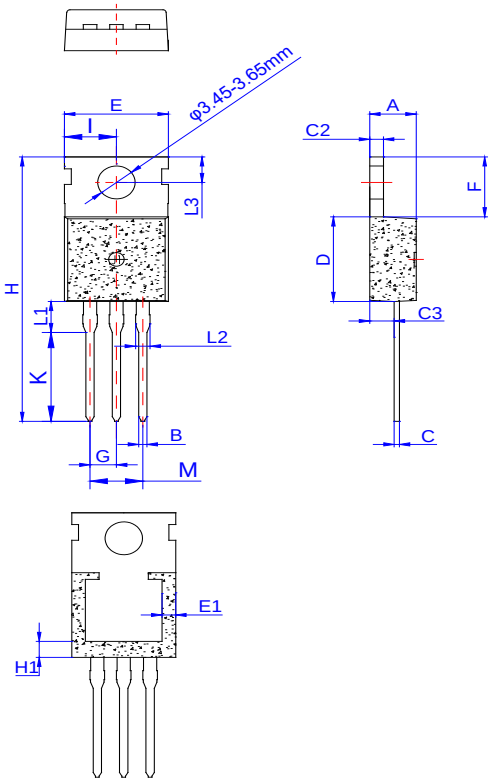
ORDERING INFORMATION

Order code	Voltage V_{DRM}/V_{RRM} (V)	IGT(μA)	Package	Base qty. (pcs)	Delivery mode
JR0405C	600	≤200	TO-220C	50	Tube

Document Revision History

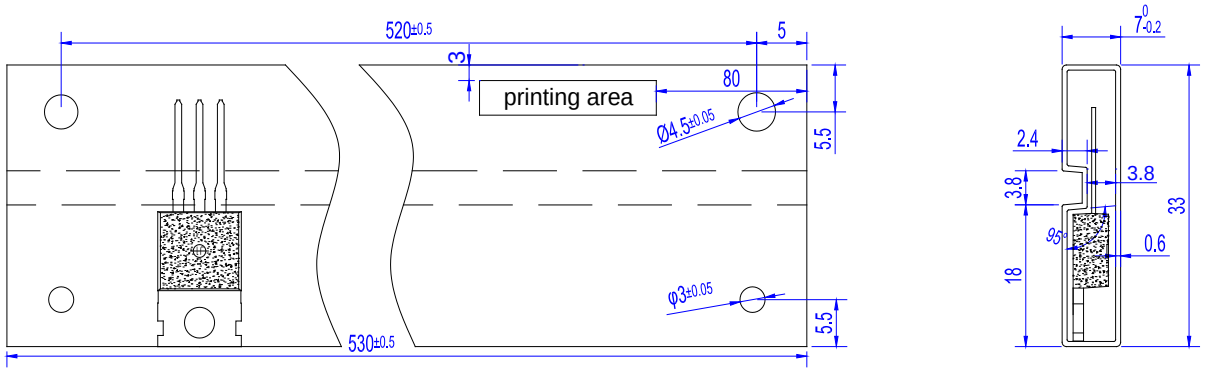
Date	Revision	Changes
Apr.10, 2023	A.1.0	Last update
Oct.15, 2025	A.1.1	Revise PACKAGE MECHANICAL DATA

PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	0.70		0.90	0.028		0.035
C	0.45		0.60	0.018		0.024
C2	1.25		1.35	0.049		0.053
C3	2.20		2.60	0.087		0.102
D	8.90		9.90	0.350		0.390
E	9.90		10.30	0.390		0.406
E1	0.80		1.20	0.031		0.047
F	6.30		6.90	0.248		0.272
G	2.40		2.70	0.094		0.106
H	28.00		29.80	1.102		1.173
H1	2.15		2.55	0.085		0.100
I	4.70		5.10	0.185		0.201
K	9.90		10.30	0.390		0.406
L1	2.70		3.30	0.106		0.130
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
M	4.80		5.20	0.189		0.205

DELIVERY MODE



PACKAGE	OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON
TO-220C	TUBE	50	1,000	5,000

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